# **General Description**

**Applications** 

The MAX4991–MAX4994 low on-resistance analog switches operate from a single +1.8V to +5.5V supply. The MAX4991/MAX4993 feature a slow turn-on time to reduce clicks and pops due to coupling capacitors and audio amplifiers with a DC output bias. This feature provides click-and-pop reduction without adding additional parts for existing architectures.

The MAX4991/MAX4992 are dual single-pole/doublethrow (SPDT) switches, while the MAX4993/MAX4994 are double-pole/double-throw (DPDT) switches. The MAX4993/MAX4994 feature an active-low enable input (EN) that sets all the channels to high impedance and reduces supply current when driven high. These devices have  $0.3\Omega$  on-resistance and 0.004% THD+N to route high fidelity audio signals.

The MAX4991–MAX4994 are available in space-saving 10-pin UTQFN (1.4mm x 1.8mm) package, and are specified for operation over the -40°C to +85°C extended temperature range.

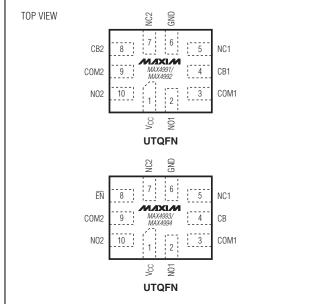
Speaker Headset Source Switching Cellular Phones Portable MP3 Players Audio Signal Routing

Typical Application Circuit appears at end of data sheet.

## **Features**

- Slow Turn-On for Click-and-Pop Reduction Without Additional Parts
- Low 0.3Ω On-Resistance
- Low Ron Flatness (1mΩ)
- Low THD+N: 0.004%
- +1.8V to +5.5V Single-Supply Operation
- ♦ 1.2µA (typ) Supply Current
- Space-Saving Packages 10-Pin UTQFN (1.4mm x 1.8mm x 0.55mm)

### \_Pin Configurations



### **Ordering Information/Selector Guide**

PART	PIN-PACKAGE	CONFIGURATION	SLOW-SWITCHING TIME	ENABLE LINE	TOP MARK
MAX4991EVB+*	10 UTQFN	Dual SPDT	Yes	No	AAD
MAX4992EVB+	10 UTQFN	Dual SPDT	No	No	AAE
MAX4993EVB+	10 UTQFN	DPDT	Yes	Yes	AAF
MAX4994EVB+*	10 UTQFN	DPDT	No	Yes	AAG

Note: All devices operate over -40°C to +85°C extended temperature range.

+Denotes a lead(Pb)-free/RoHS-compliant package.

\*Future product—contact factory for availability.

*Maxim Integrated Products* 1

n) tions

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, WWW.DataSheet 40.com, s website at www.maxim-ic.com.

### **ABSOLUTE MAXIMUM RATINGS**

(Voltages referenced to GND.)

(	
V <sub>CC</sub> , CB_, <u>EN</u>	0.3V to +6.0V
COM_, NC_, NO0.3V t	to (V <sub>CC</sub> + 0.3V)
Continuous Current COM_, NC_, NO	±350mA
Peak Current COM_, NC_, NO_ (pulsed at 1ms,	
50% duty cycle)	±700mA
Peak Current COM_, NC_, NO_ (pulsed at 1ms,	
10% duty cycle)	±1.5A
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
10-Pin UTQFN (derate 6.9mW/°C above +70°C	C)559mW

Junction-to-Case Thermal Resistance $(\theta_{JC})$ (N	lote 1)
10-Pin UTQFN	20.1°C/W
Junction-to-Ambient Thermal Resistance ( $\theta_{JA}$ )	) (Note 1)
10-Pin UTQFN	143.1°C/W
Operating Temperature Range	40°C to +85°C
Junction Temperature Range	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a 4-layer board. For detailed information on package thermal considerations, refer to <u>www.maxim-ic.com/thermal-tutorial</u>.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = +2.7V \text{ to } +5.5V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted. Typical values are at V_{CC} = +3.0V, T_A = +25^{\circ}C.)$  (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
Power-Supply Range	V <sub>CC</sub>			1.8		5.5	V
Undervoltage Lockout	Vuvlo				1.4		V
		$V_{CB1} = V_{CB2} = 0V \text{ or } V_{CC}$	$V_{CC} = +3V$		1.2	2.5	
Supply Current			$V_{CC} = +5.5V$		3.1	6	]
(MAX4991/MAX4992)	Icc	$V_{CB1} = V_{CB2} = +0.5V$ or	$V_{CC} = +2.7V$			3	- μΑ -
		+1.4V	$V_{CC} = +5.5V$			14	
		$V_{\overline{EN}} = V_{CC}, V_{CB} = 0V \text{ or } V_{CC}$	$V_{\rm CC} = +5.5V$		0.1	1	μΑ
			$V_{CC} = +3V$		1.2	2.5	
Supply Current (MAX4993/MAX4994)	Icc	$V_{\overline{EN}} = 0V, V_{CB} = 0V \text{ or } V_{CC}$	$V_{CC} = +5.5V$		3.1	6	
	VE	$V_{\overline{EN}} = V_{CB} = +0.5V \text{ or } +1.4V$	$V_{CC} = +2.7V$			3	
			$V_{CC} = +5.5V$			8.5	
Power-Supply Rejection Ratio	PSRR	$R_L = R_S = 50\Omega$ , f = 20kHz			80		dB
Analog Signal Range	V <sub>NC_</sub> , V <sub>NO_</sub> , V <sub>COM_</sub>			0		V <sub>CC</sub>	V
On Desistance	R <sub>ON</sub>	$V_{CC} = +2.7V, V_{NC}$ or $V_{NO} = 0$	$T_A = +25^{\circ}C$		0.3	0.5	- Ω
On-Resistance		to V <sub>CC</sub> , $I_{COM}$ = 100mA	$T_A = T_{MIN}$ to $T_{MAX}$			0.6	
On-Resistance Match Between Channels	ΔR <sub>ON</sub>	$V_{CC}$ = +2.7V, between NC_, NO_ only, I <sub>COM</sub> = 100mA, V <sub>NC</sub> or V <sub>NO</sub> = V <sub>CC</sub> /2			3		mΩ
On-Resistance Flatness	R <sub>FLAT</sub>	$V_{CC} = +2.7V$ , $V_{NC}$ or $V_{NO} = 0$ to $V_{CC}$ , $I_{COM} = 100mA$ (Note 3)			1		mΩ
	out Noise NCOM_		f = 20Hz to 20kHz		1		
COM_ Output Noise		$V_{\text{NC}} = V_{\text{NO}} = 0V, R_{\text{L}} = 50\Omega$	f = 0Hz to $1MHz$		50		μVRMS

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = +2.7V \text{ to } +5.5V, T_A = -40^{\circ}C \text{ to } +85^{\circ}C, \text{ unless otherwise noted. Typical values are at } V_{CC} = +3.0V, T_A = +25^{\circ}C.)$  (Note 2)

$\begin{array}{c c} NC_{,} NO_{,} Off-Leakage \\ Current \\ l_{L(OFF)} \\ l_{L(OFF)} \\ VCC = +2.7V, switch open, VNC_{,} or VNO_{,} = 0V \\ or VCC, VCOM_{,} = VCC or 0V \\ Or VCC, VCOM_{,} = VCC or 0V \\ or VCC, VCOM_{,} = VCC, VNC_{,} or VNO_{,} = 0V \\ or VCC, VCOM_{,} = VCC or 0V \\ Or VCC, VCOM_{,} = VCC or 0V \\ Or VCC, VCOM_{,} = VCC, VNO_{,} or VNO_{,} = 0V, \\ VCC = +2.7V, switch closed, VNC_{,} or VNO_{,} = 0V, \\ VCC or unconnected, VCOM_{,} = 0V, VCC, or \\ UCC or unconnected \\ \\ \hline DYNAMIC \\ \hline \\ Turn-On Time \\ (Note 4) (Figure 1) \\ ton \\ \hline \\ ton \\ \hline \\ tor \\ VISO \\ \hline \\ Off-Isolation \\ Off-Isolation \\ VISO \\ \hline \\ Crosstalk \\ VCT \\ \hline \\ Tutharmonic Distortion \\ THD+N \\ \hline \\ Figure 2 (Note 5) \\ \hline \\ Com_{,} NO_{,} Off-Capacitance \\ COFF \\ \hline \\ VCC \\ Figure 2 (Note 5) \\ \hline \\ COM_{,} = GND (DC bias), f = 1MHz, \\ VNO(KC) = 100mVP.P, (Figure 3) \\ \hline \\ COM_{,} On-Capacitance \\ CON \\ \hline \\ \hline \\ DIGITAL I/O (CB, CB1, CB2, EN) \\ \hline \\ Input Logic-Ling \\ VIE \\ \hline \\ \hline \\ Input Logic-Low \\ VIE \\ \hline \\ \hline \\ \end{array}$	ι τγρ	MAX	UNITS
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	0	+100	nA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0	+100	nA
Turn-On Time (Note 4) (Figure 1)ton $V_{CC} = +2.7V, V_{NC} or V_{NO} = +1.5V, R_L = 50\Omega, C_L = 35pF (MAX4991/MAX4993)12Turn-Off TimetoffV_{CC} = +2.7V, V_{NC} or V_{NO} = +1.5V, R_L = 50\Omega, C_L = 35pF (MAX4992/MAX4994)1Turn-Off TimetoffV_{CC} = +2.7V, V_{NC} or V_{NO} = +1.5V, R_L = 50\Omega, C_L = 35pF (MAX4992/MAX4994)1Off-IsolationV_{ISO}R_S = R_L = 50\Omega, f = 20kHz, V_{COM} = 1V_{P-P}, Figure 2 (Note 4)1Off-IsolationV_{ISO}R_S = R_L = 50\Omega, f = 20kHz, V_{COM} = 1V_{P-P}, Figure 2 (Note 5)1Total Harmonic DistortionTHD+Nf = 20Hz to 20kHz, V_{COM} = 0.5V_{P-P}, R_S = R_L = 50\Omega, DC bias = 0V1NC_, NO_Off-CapacitanceC_{OFF}COM_{-} = GND (DC bias), f = 1MHz, V_{NO(NC)} = 100mV_{P-P} (Figure 3)1DIGITAL I/O (CB, CB1, CB2, EN)VIH1.4$	60	140	nA
$ \begin{array}{c} \text{Turn-On Time} \\ (\text{Note 4}) (\text{Figure 1}) \end{array} \qquad \begin{array}{c} \text{ton} \\ \begin{array}{c} \text{ton} \end{array} \\ \hline \text{ton} \end{array} \\ \begin{array}{c} \text{CL} = 35\text{pF} (\text{MAX4991}/\text{MAX4993}) \\ \hline \text{V}_{\text{CC}} = +2.7\text{V}, \text{V}_{\text{NC}} \text{ or V}_{\text{NO}} = +1.5\text{V}, \text{RL} = 50\Omega, \\ \text{CL} = 35\text{pF} (\text{MAX4992}/\text{MAX4994}) \\ \hline \text{Turn-Off Time} \end{array} \\ \begin{array}{c} \text{tofFF} \end{array} \\ \begin{array}{c} \text{V}_{\text{OFF}} \end{array} \\ \begin{array}{c} \text{V}_{\text{CC}} = +2.7\text{V}, \text{V}_{\text{NC}} \text{ or V}_{\text{NO}} = +1.5\text{V}, \text{RL} = 50\Omega, \\ \text{CL} = 35\text{pF}, \text{Figure 1} (\text{Note 4}) \\ \hline \text{Off-Isolation} \end{array} \\ \begin{array}{c} \text{V}_{\text{ISO}} \end{array} \\ \begin{array}{c} \text{Rs} = \text{RL} = 50\Omega, \text{ f} = 20\text{kHz}, \text{V}_{\text{COM}} = 1\text{VP-P}, \\ \text{Figure 2} (\text{Note 5}) \\ \hline \text{Crosstalk} \end{array} \\ \begin{array}{c} \text{V}_{\text{CT}} \end{array} \\ \begin{array}{c} \text{Rs} = \text{RL} = 50\Omega, \text{ f} = 20\text{kHz}, \text{V}_{\text{COM}} = 1\text{VP-P}, \\ \text{Figure 2} (\text{Note 6}) \\ \hline \text{Total Harmonic Distortion} \end{array} \\ \begin{array}{c} \text{THD} + \text{N} \end{array} \\ \begin{array}{c} \text{f} = 20\text{Hz to } 20\text{kHz}, \text{V}_{\text{COM}} = 0.5\text{VP-P}, \\ \text{Rs} = \text{RL} = 50\Omega, \text{DC bias} = 0\text{V} \\ \hline \text{NC}_{-}, \text{NO}_{-} \text{Off-Capacitance} \end{array} \\ \begin{array}{c} \text{COFF} \end{array} \\ \begin{array}{c} \text{COM}_{-} = \text{GND} (\text{DC bias}), \text{f} = 1\text{MHz}, \\ \text{V}_{\text{NO}(\text{NC})} = 100\text{mVP-P}, (\text{Figure 3}) \\ \hline \text{COM}_{-} = 0.5\text{V}_{\text{P},\text{P}}, \\ \hline \text{Rs} = 100\text{mVP-P}, (\text{Figure 3}) \end{array} \\ \end{array} \\ \begin{array}{c} \text{DIGITAL I/O (CB, CB1, CB2, \overline{EN})} \\ \end{array} $			
(Note 4) (Figure 1) $V_{CC} = +2.7V, V_{NC_orv_{NO_e}} = +1.5V, R_L = 50\Omega, C_L = 35pF (MAX4992/MAX4994)$ Turn-Off Time $t_{OFF}$ $V_{CC} = +2.7V, V_{NC_orv_{NO_e}} = +1.5V, R_L = 50\Omega, C_L = 35pF, Figure 1 (Note 4)$ Off-Isolation $V_{ISO}$ $R_S = R_L = 50\Omega, f = 20kHz, V_{COM_e} = 1V_{P-P}, Figure 2 (Note 5)$ Crosstalk $V_{CT}$ $R_S = R_L = 50\Omega, f = 20kHz, V_{COM_e} = 1V_{P-P}, Figure 2 (Note 6)$ Total Harmonic Distortion $THD + N$ $f = 20Hz to 20kHz, V_{COM_e} = 0.5V_{P-P}, R_S = R_L = 50\Omega, DC bias = 0V$ NC_, NO_Off-Capacitance $C_{OFF}$ $COM_e = GND (DC bias), f = 1MHz, V_{NO(NC)} = 100mV_{P-P}, (Figure 3)$ COM_On-Capacitance $C_{ON}$ $COM_e = GND (DC bias), f = 1MHz, V_{COM_e} = 100mV_{P-P}, (Figure 3)$ DIGITAL I/O (CB, CB1, CB2, EN) $V_{IH}$ $I.4$	) 360	630	ms
Turn-On TimetOFF $C_L = 35pF$ , Figure 1 (Note 4)Off-Isolation $V_{ISO}$ $R_S = R_L = 50\Omega$ , $f = 20kHz$ , $V_{COM} = 1V_{P-P}$ , Figure 2 (Note 5)Crosstalk $V_{CT}$ $R_S = R_L = 50\Omega$ , $f = 20kHz$ , $V_{COM} = 1V_{P-P}$ , Figure 2 (Note 6)Total Harmonic Distortion $THD+N$ $f = 20Hz$ to $20kHz$ , $V_{COM} = 0.5V_{P-P}$ , $R_S = R_L = 50\Omega$ , DC bias = $0V$ NC_, NO_Off-Capacitance $C_{OFF}$ $COM_{-} = GND$ (DC bias), $f = 1MHz$ , $V_{NO(NC)} = 100mV_{P-P}$ , (Figure 3)COM_On-Capacitance $C_{ON}$ $COM_{-} = GND$ (DC bias), $f = 1MHz$ , $V_{COM} = 100mV_{P-P}$ (Figure 3)DIGITAL I/O (CB, CB1, CB2, EN) $V_{IH}$ $I.4$	20	150	μs
Oli-IsolationVISOFigure 2 (Note 5)Crosstalk $V_{CT}$ $R_S = R_L = 50\Omega, f = 20 \text{ Hz}, V_{COM} = 1 \text{ VP-P}, Figure 2 (Note 6)Total Harmonic DistortionTHD+Nf = 20 \text{ Hz} \text{ to } 20 \text{ Hz}, V_{COM} = 0.5 \text{ VP-P}, R_S = R_L = 50\Omega, DC \text{ bias} = 0VNC_, NO_Off-CapacitanceC_{OFF}COM_{-} = GND (DC \text{ bias}), f = 1 \text{ MHz}, V_{NO(NC)} = 100 \text{ mVP-P}, (Figure 3)COM_On-CapacitanceC_{ON}COM_{-} = GND (DC \text{ bias}), f = 1 \text{ MHz}, V_{COM} = 100 \text{ mVP-P} (Figure 3)DIGITAL I/O (CB, CB1, CB2, EN)I.4$	0.5	2	μs
ClossfaikVCIFigure 2 (Note 6)Total Harmonic DistortionTHD+N $f = 20Hz to 20kHz, V_{COM} = 0.5VP-P, R_S = R_L = 50\Omega, DC bias = 0V$ NC_, NO_Off-CapacitanceCOFFCOM_ = GND (DC bias), f = 1MHz, V_{NO(NC)} = 100mVP-P, (Figure 3)COM_On-CapacitanceCONCOM_ = GND (DC bias), f = 1MHz, V_{COM} = 100mVP-P, (Figure 3)DIGITAL I/O (CB, CB1, CB2, EN)Input Logic-HighVIH	-90		dB
Total Harmonic DistortionTHD+N $R_S = R_L = 50\Omega$ , DC bias = 0VNC_, NO_Off-Capacitance $C_{OFF}$ $COM_{-} = GND (DC bias), f = 1MHz, V_{NO(NC)} = 100mV_{P-P}, (Figure 3)COM_On-CapacitanceC_{ON}COM_{-} = GND (DC bias), f = 1MHz, V_{COM} = 100mV_{P-P} (Figure 3)DIGITAL I/O (CB, CB1, CB2, EN)Input Logic-HighVIH$	-110	I	dB
NC_, NO_Off-Capacitance         COFF         V <sub>NO(NC)</sub> = 100mV <sub>P-P</sub> , (Figure 3)           COM_On-Capacitance         CON         COM_ = GND (DC bias), f = 1MHz, V <sub>COM</sub> = 100mV <sub>P-P</sub> (Figure 3)           DIGITAL I/O (CB, CB1, CB2, EN)         Input Logic-High         VIH	0.004	4	%
COM_On-Capacitance         CON         V <sub>COM</sub> = 100mV <sub>P-P</sub> (Figure 3)           DIGITAL I/O (CB, CB1, CB2, EN)         Input Logic-High         V <sub>IH</sub> 1.4	45		pF
Input Logic-High VIH 1.4	65		pF
Input Logic-Low VIL			V
		0.5	V
Input Leakage Current $I_{CB}$ $V_{CB_{-}} = V_{\overline{EN}} = 0V \text{ or } V_{CC}$ -1		+1	μA

**Note 2:** All devices are 100% production tested at  $T_A = +25$ °C. All temperature limits are guaranteed by design.

Note 3: Flatness is defined as the difference between the maximum and minimum values of on-resistance as measured over the specified analog ranges.

Note 4: All timing is measured using 10% and 90% levels.

Note 5: Off-isolation =  $20\log [V_{COM_{-}}(V_{NO_{-}} \text{ or } V_{NC_{-}})]$ ,  $V_{COM_{-}} = \text{output}$ ,  $V_{NO_{-}} \text{ or } V_{NC_{-}} = \text{input to off switch}$ .

Note 6: Between any two switches.

M /X / M

M/IXI/N

# Low Ron, Dual-SPDT/Single-DPDT Analog Switches with Slow Turn-On Time

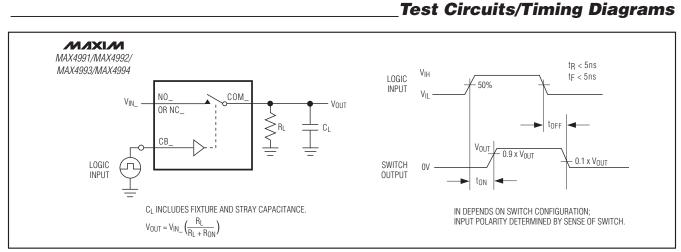


Figure 1. Switching Time

MAX4991-MAX4994

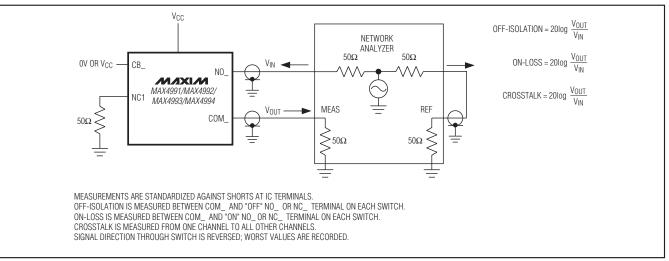


Figure 2. On-Loss, Off-Isolation, and Crosstalk

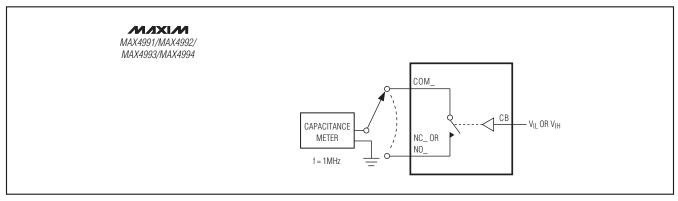


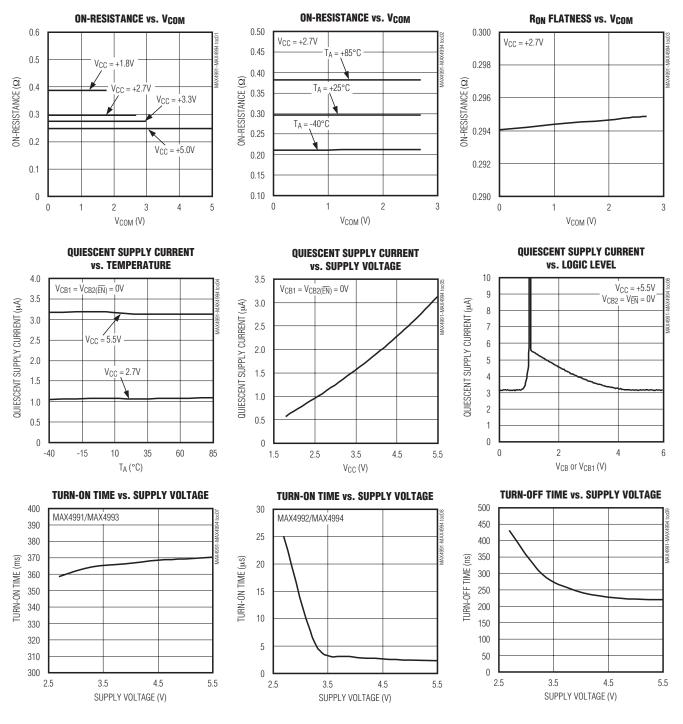
Figure 3. Channel Off-/On-Capacitance

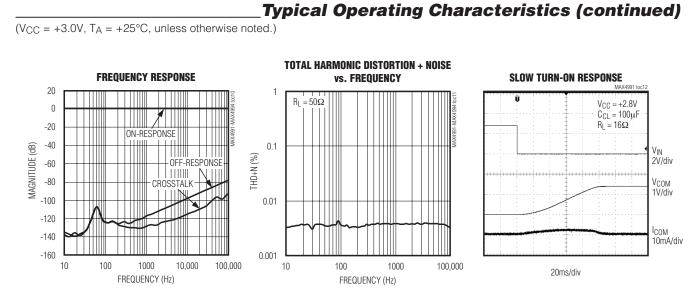
**MAX4991-MAX4994** 

Typical Operating Characteristics

# Low Ron, Dual-SPDT/Single-DPDT Analog Switches with Slow Turn-On Time

(V<sub>CC</sub> = +3.0V,  $T_A$  = +25°C, unless otherwise noted.)

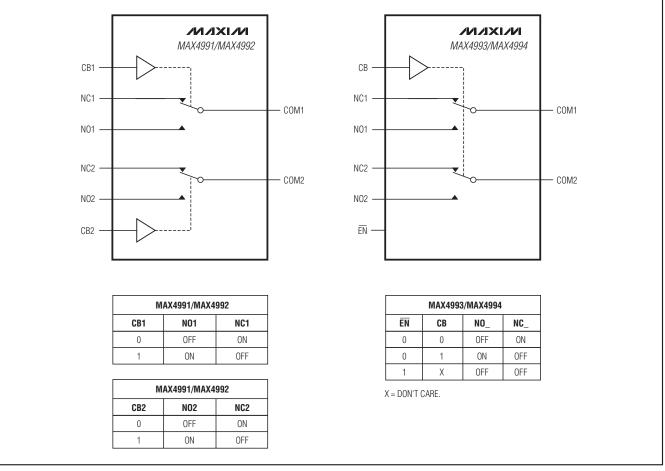




# **Pin Description**

M/IXI/M

Р	IN	NAME	FUNCTION		
MAX4991/MAX4992	MAX4993/MAX4994	NAME	FUNCTION		
1	1	V <sub>CC</sub>	Positive-Supply Voltage Input. Bypass $V_{CC}$ to GND with a 0.1 $\mu\text{F}$ capacitor as close as possible to the device.		
2	2	NO1	Analog Switch 1—Normally Open Terminal		
3	3	COM1	Analog Switch 1—Common Terminal. COM1 must be connected to the speaker load for click-and-pop reduction.		
4	—	CB1	Digital Control Input for Switch 1		
—	4	CB	Digital Control Input for Switch 1 and Switch 2		
5	5	NC1	Analog Switch 1—Normally Closed Terminal		
6	6	GND	Ground		
7	7	NC2	Analog Switch 2—Normally Closed Terminal		
8	—	CB2	Digital Control Input for Switch 2		
_	8	ĒN	Active-Low Enable Input—Drive $\overline{\text{EN}}$ high to put switches in high impedance. Drive $\overline{\text{EN}}$ low for normal operation.		
9	9	COM2	Analog Switch 2—Common Terminal. COM2 must be connected to the speaker load for click-and-pop reduction.		
10	10	NO2	Analog Switch 2—Normally Open Terminal		



### Functional Diagram

### **Detailed Description**

The MAX4991–MAX4994 low  $0.3\Omega$  (typ) on-resistance analog switches have break-before-make switching and operate from a single +1.8V to +5.5V supply. The MAX4991/MAX4993 provide a slow turn-on time, and with COM\_ used as the output, reduce clicks and pops due to coupling capacitors and audio amplifiers with a DC output bias. This feature is important for existing architectures with coupling capacitors at the output that need click-and-pop reduction.

The MAX4993/MAX4994 DPDT switches with an activelow enable input  $(\overline{EN})$  set all channels to high impedance and reduce supply current when driven high. The MAX4991–MAX4994 have a low 0.004% THD+N to route high-fidelity audio signals.

#### **Digital Control Input**

The MAX4991/MAX4992 have two digital control logic inputs, CB1 and CB2. The MAX4993/MAX4994 have a single digital-control logic input, CB. The digital control logic inputs control the position of the corresponding switch as shown in the *Functional Diagram*. Driving logic inputs rail-to-rail minimizes power consumption.

#### Enable Input (MAX4993/MAX4994)

The MAX4993/MAX4994 feature an active-low enable input (EN). When EN is driven high, the switches are high impedance and reduce supply current. When EN is driven low, the MAX4993/MAX4994 operate in normal mode. Driving EN rail-to-rail minimizes power consumption.





#### **Analog Signal Levels**

The MAX4991–MAX4994 have a very low and stable R<sub>ON</sub>, 0.3 $\Omega$  (typ), as the analog input signals are swept from ground to V<sub>CC</sub> (see *Typical Operating Characteristics*). These switches are bidirectional, allowing NO\_, NC\_, and COM\_ to be configured as either inputs or outputs; however, click-and-pop reduction is only operational when COM\_ is used as the output.

#### **Power-Supply Rejection Ratio**

PSRR is the measurement of AC power-supply ripple or noise that couples to the output. Variations in supply voltage corrupt the audio signal due to changes in the R<sub>ON</sub> value by supply modulation. The MAX4991–MAX4994 maintain a 80dB (typ) PSRR across the supply-voltage range, eliminating any corruption of the audio signal from supply variations. Therefore, with no audio signal, the R<sub>ON</sub> variation due to supply-voltage ripple does not contribute to any output signal modulation.

#### **Applications Information**

#### **Click-Pop Reduction**

The MAX4991/MAX4993 feature a slow switch turn-on that can reduce click-and-pop noise caused by abrupt changes in voltage across a speaker. These voltage

changes usually occur when a single-supply audio amplifier with a DC bias is turned on, causing a spike of current in the speaker while the coupling capacitor charges (see the *Typical Operating Circuit*). If the audio amplifier connected to the unused input is powered up before the switch position changes, the MAX4991/ MAX4993 reduce the current spike to COM\_. The speaker load must be present so that the current charging the coupling capacitor has a path to ground.

#### Layout

Good layout improves performance by decreasing the amount of stray capacitance and noise. Minimize PCB trace lengths and resistor leads and place external components as close as possible to the device.

#### **Power-Supply Sequencing**

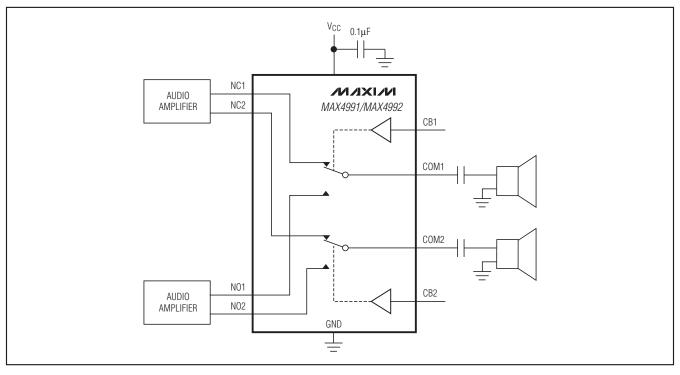
Caution: Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device.

Proper power-supply sequencing is recommended for all devices. Always apply  $V_{CC}$  before applying analog signals especially if the analog signal is not current limited.

MAX4991-MAX4994

# Low Ron, Dual-SPDT/Single-DPDT Analog Switches with Slow Turn-On Time

# \_Typical Application Circuit



**Chip Information** 

PROCESS: BiCMOS

### **Package Information**

For the latest package outline information and land patterns, go to **www.maxim-ic.com/packages**.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.		
10 UTQFN	V101AICN-1	<u>21-0028</u>		

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	5/08	Initial release.	
1	6/09	<ul> <li>Corrected names of power pins (added subscripting) in <i>Electrical Characteristics</i>.</li> <li>Changed the name of <i>TOC 10</i> to "Frequency Response."</li> <li>Added units of measure to <i>TOC 12</i>.</li> </ul>	2, 6

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